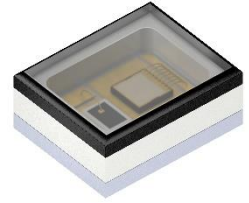


V102C121A-850

BIDOS® P2835 C

VCSEL pulsed laser in small footprint ceramic with power monitor diode



Applications

- Virtual Reality
- 3D Sensing
- Industrial Automation
- Access Control (IRIS/Vein Scan, Face Recognition)
- Augmented Reality, Mixed Reality
- Flash & Autofocus
- Gesture Recognition

Features:

- Package: SMD ceramic package with glass diffuser window
- Chip Technology: GaAs VCSEL power array
- IR Laser Wavelength: 850 nm
- Optical Power Class: 2 W pulsed
- Radiation Profile: 60°x45° (Rectangular emission profile)
- ESD: 8 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 3B)
- Power monitoring diode

Ordering Information

Type	Operational Mode: $I_F = 2.5A$, $T_S = 25^\circ C$ $t_p = 100\mu S$, DC = 1%	Ordering Code
V102C121A-850	2W	Q65112A9365

Depending on the mode of operation, these devices emit highly concentrated visible and non-visible light which can be hazardous to the human eye. Products which incorporate these devices must follow the safety precautions given in the “Notes” section.

Maximum Ratings

$T_a = 25^\circ\text{C}$

Parameter	Symbol		Values
Operation/Solder temperature $t_p = 100 \mu\text{s}$; DC = 1 %	T_s	min.	-40 °C
		max.	100 °C
Storage temperature	T_{stg}	min.	-40 °C
		max.	100 °C
Forward current Pulsed operation; $T_p = 100 \mu\text{s}$; DC = 1 %; $T_s = 25^\circ\text{C}$	I_f	max.	7 A
Forward current Direct current operation; DC = 100%; $T_s = 25^\circ\text{C}$	I_f	max.	4.5 A
Reverse Voltage	Not designed for reverse operation		
Reflow soldering temperature	T_{Ref}	max.	260 °C
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 3B)	V_{ESD}	max.	8 kV

Note: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device.

Characteristics

$T_a = 25^\circ\text{C}$, $I_F = 2.5\text{ A}$; $t_p = 100\mu\text{s}$; DC = 1%

Parameter	Symbol		Values
Forward voltage	V_F	typ.	2.2 V
Output power	Φ	typ.	2.0 W
Threshold current	I_{th}	typ.	0.46 A
Slope efficiency	SE	typ.	1.0 W / A
Power conversion efficiency	η	typ.	37 %
Peak wavelength	λ_{peak}	min.	840 nm
		typ.	850 nm
		max.	860 nm
Spectral bandwidth at FWHM (50% of Φ_{max})	λ_{FWHM}	typ.	2 nm
Temperature coefficient of wavelength	TC_λ	typ.	0.06 nm / K
Field of view at FWHM (HFOV)	$\theta_{ }$	typ.	60 °
Field of view at FWHM (VFOV)	θ_{\perp}	typ.	45 °
Thermal resistance junction/solder point	$R_{th, JS}$	typ.	15.9 K / W

Power Monitoring Diode Characteristics

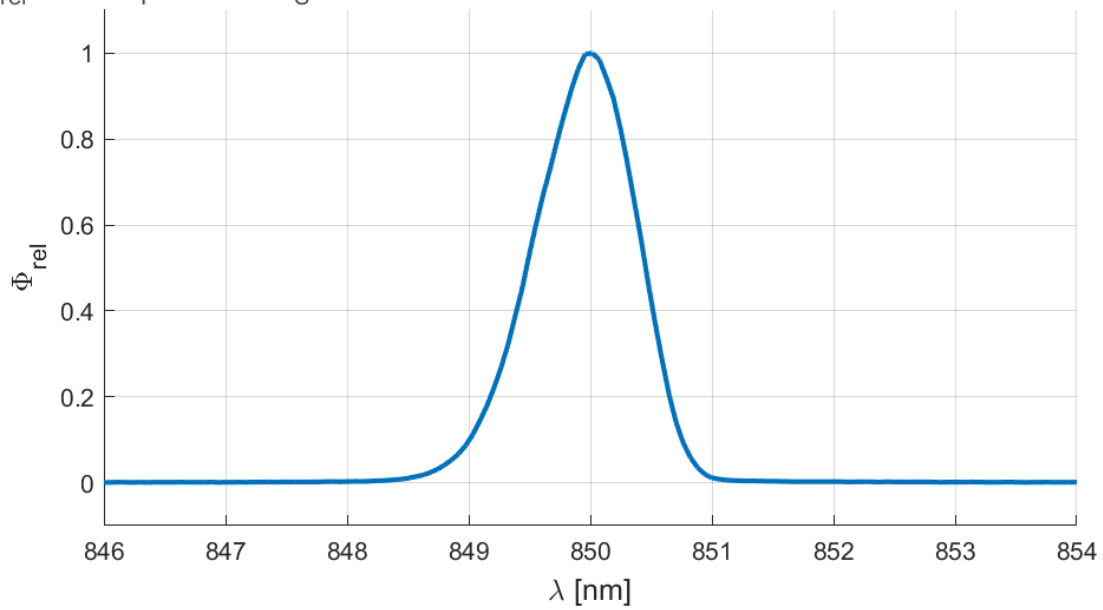
$T_a = 25^\circ\text{C}$

Parameter	Symbol		Values
PMD Sensitivity	P_s	typ.	1.4 $\mu\text{A}/\mu\text{W}$
$L_{op} = 1.7 \text{ to } 2.3\text{W}$			
Reverse Breakdown Voltage	V_{Br}	min.	50 V
Reverse Dark Current	I_{Dark}	max.	1.0 nA
Rise time	t_r	typ.	1 ns
10% and 90% of $I_{PMD \max}$			
Fall time	t_f	typ.	1 ns
10% and 90% of $I_{PMD \max}$			

Note: Sensor performance parameters are effective over the designated optical operating power (Φ_{op}) range listed in the section "electro-optical characteristics of VCSEL".

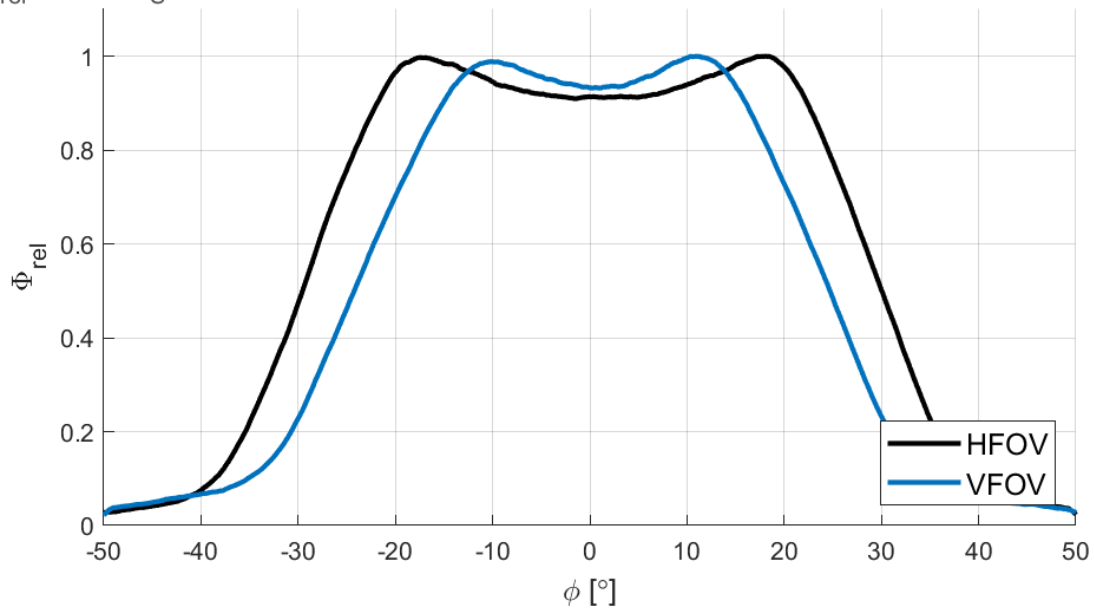
Relative Spectral Emission ¹⁾

$$\Phi_{\text{rel}} = f(\lambda); I_F = 2.6 \text{ A}; T_S = 25 \text{ }^\circ\text{C}$$

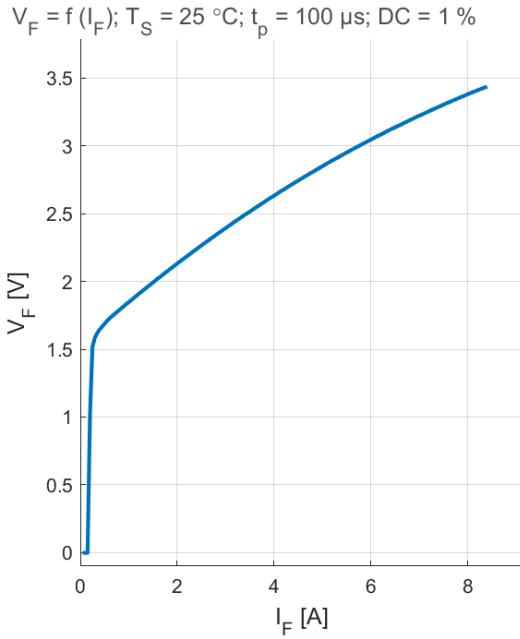


Radiation Characteristics ¹⁾

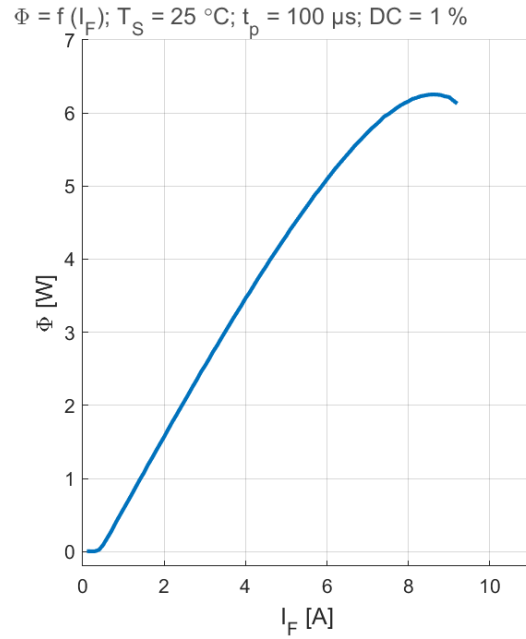
$$\Phi_{\text{rel}} = f(\phi); T_S = 20 \text{ }^\circ\text{C}$$



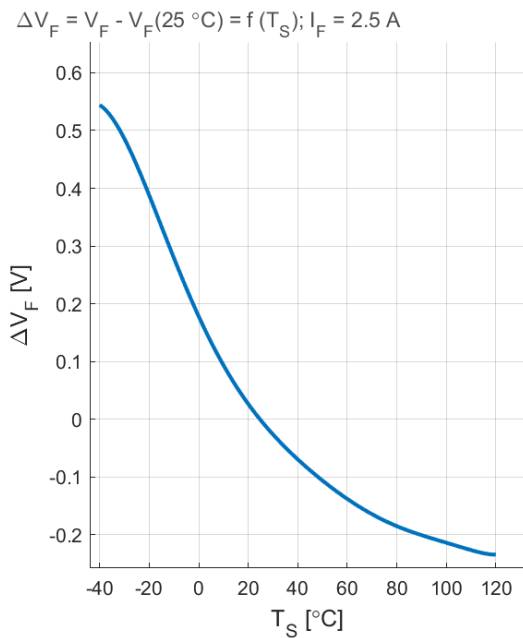
Forward Voltage 1) 2)



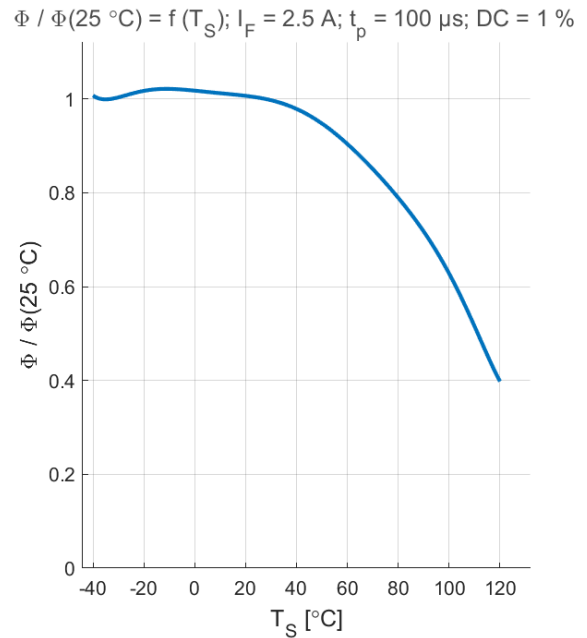
Optical Output Power 1) 2)



Relative Forward Voltage 1)

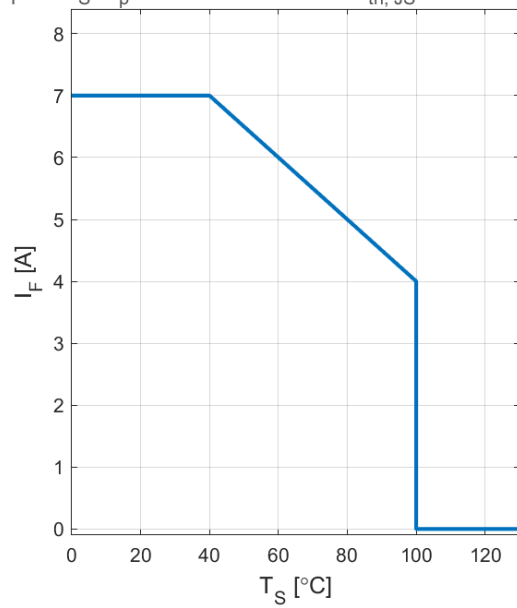


Relative Radiant Power 1)



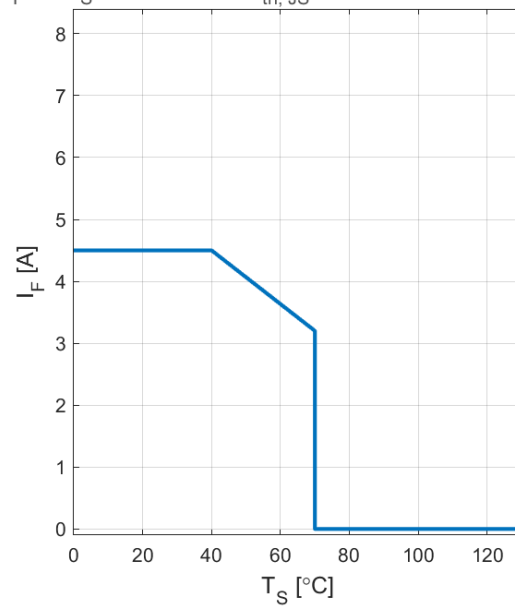
Max Permissible Pulse Current

$$I_F = f(T_S); t_p = 100 \mu\text{s}; \text{DC} = 1\%; R_{th, JS} = 15.9 \text{ K/W}$$



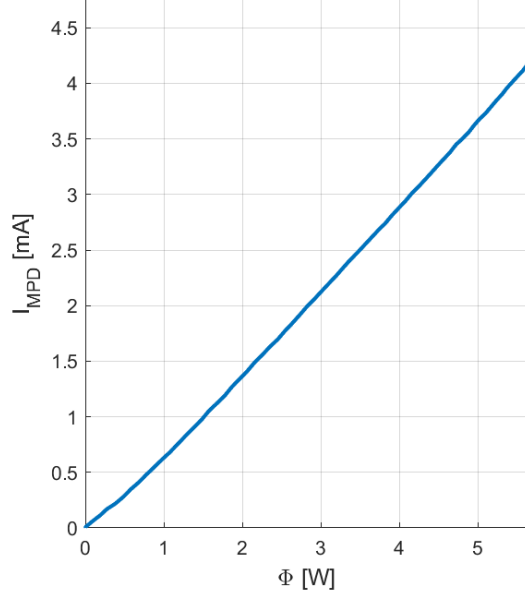
Max Permissible Current

$$I_F = f(T_S); \text{DC} = 100\%; R_{th, JS} = 15.9 \text{ K/W}$$

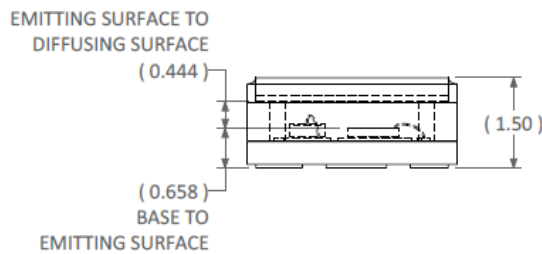
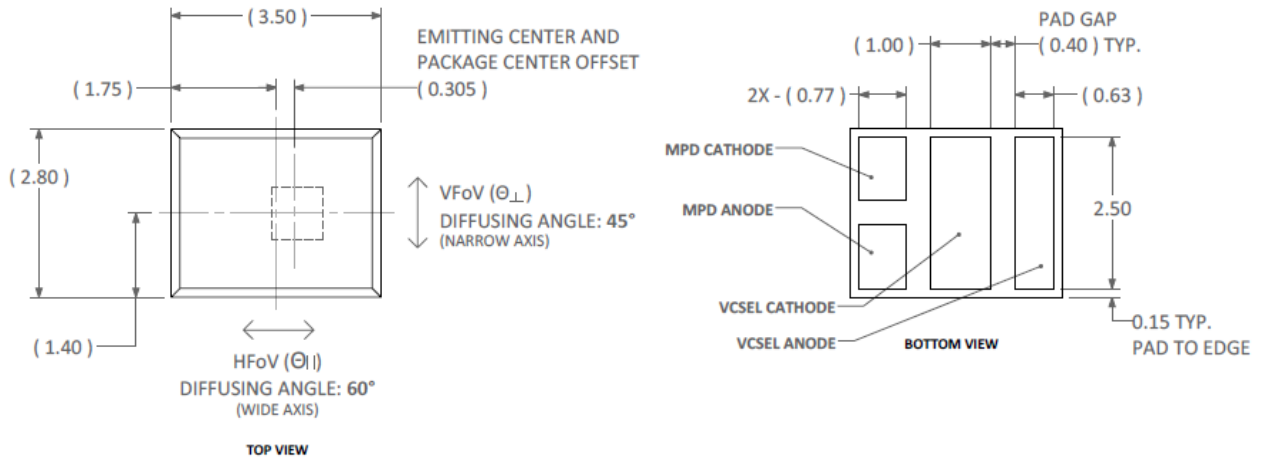


Monitor Photodiode Responsivity

$$I_{MPD} = f(\Phi); T_S = 25 \text{ °C}; t_p = 100 \mu\text{s}; \text{DC} = 1\%$$



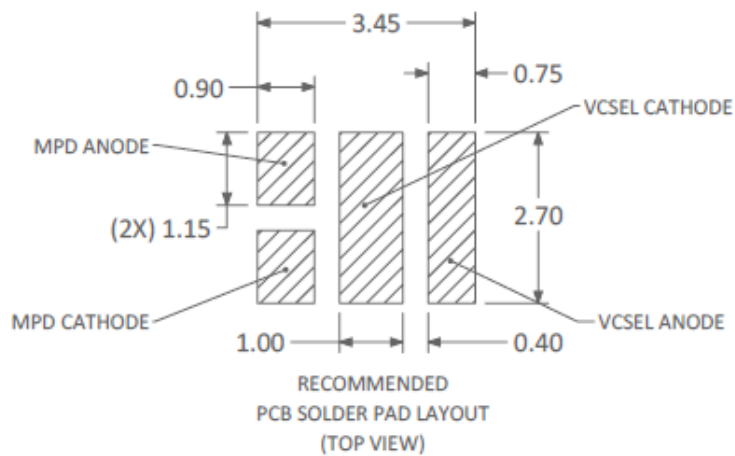
Dimension Drawings ³⁾



Further Information

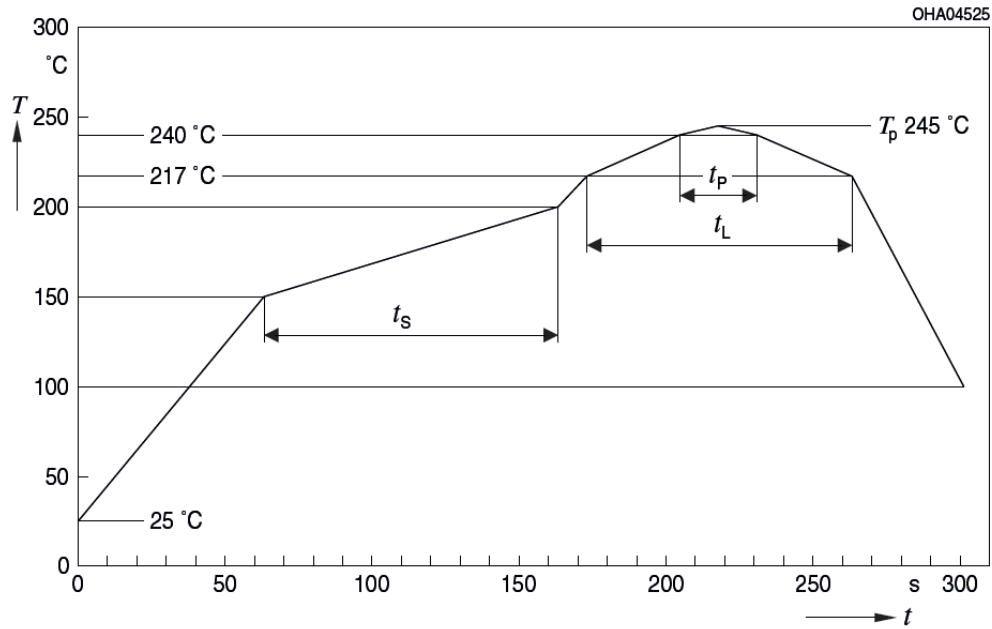
Approximate Weight: 38 mg

Recommended Solder Pad Layout ³⁾



Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E

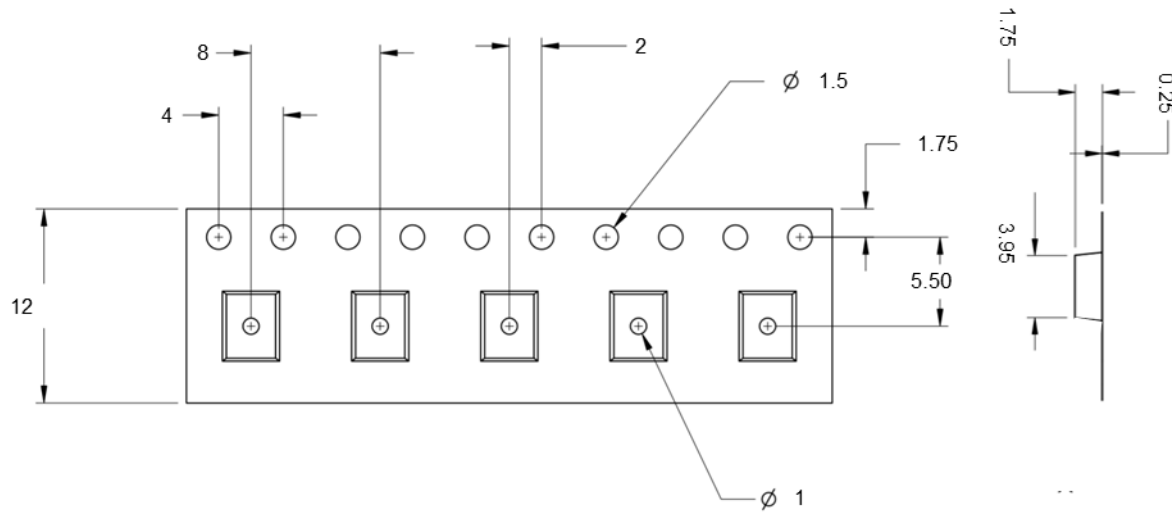


Profile Feature	Symbol	Pb-Free (SnAgCu) Assembly			Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat*) 25°C to 150°C			2	3	K/s
Time t_s T_{smin} to T_{smax}	t_s	60	100	120	s
Ramp-up rate to peak*) T_{smax} to T_P			2	3	K/s
Liquidus temperature	T_L		217		°C
Time above liquidus temperature	t_L		45	60	s
Peak temperature	T_P		245	260	°C
Time within 5 °C of the specified peak temperature $T_P - 5$ K	t_p	10	20	30	s
Ramp-down rate*) T_P to 100°C			3	6	K/s
Time 25°C to T_P				480	s

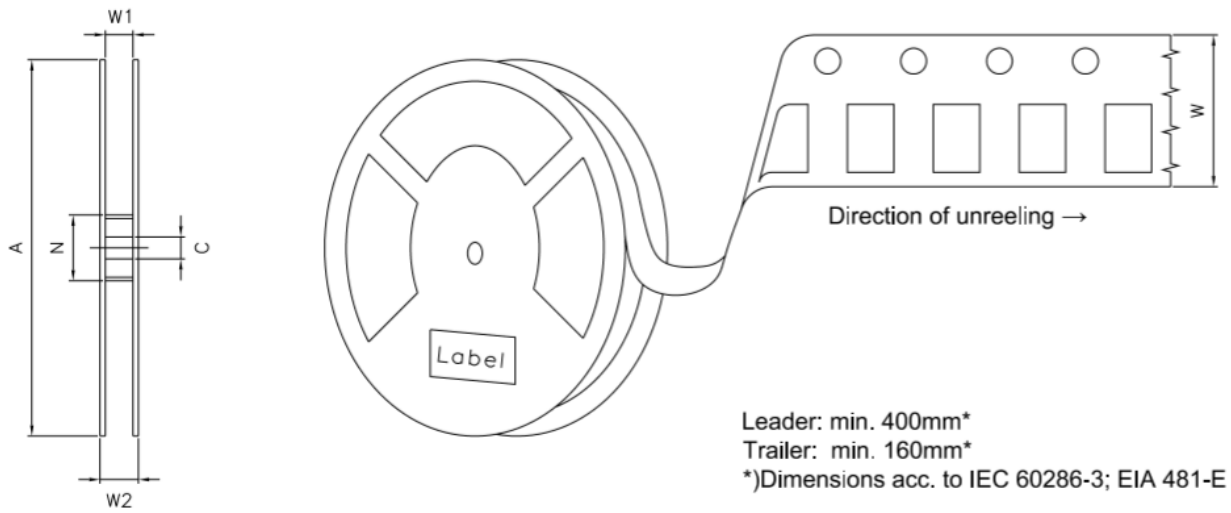
All temperatures refer to the center of the package, measured on the top of the component

*)slope calculation DT/Dt : Dt max. 5s; fulfillment for the whole T-range

Taping ^{3) 4)}



Tape and Reel ⁴⁾



Reel dimensions [mm]

A	W	N _{min}	W ₁	W _{2 max}	Pieces per PU
330 mm	12 + 0.3 / - 0.1	60	12.4 + 2	18.4	2500

Barcode-Product-Label (BPL)

Vixar
a company of
OSRAM
Opto Semiconductors

LX XXXX BIN1:XX-XX-X-XXX-X

RoHS Compliant

(6P) BATCH NO: 1234567890

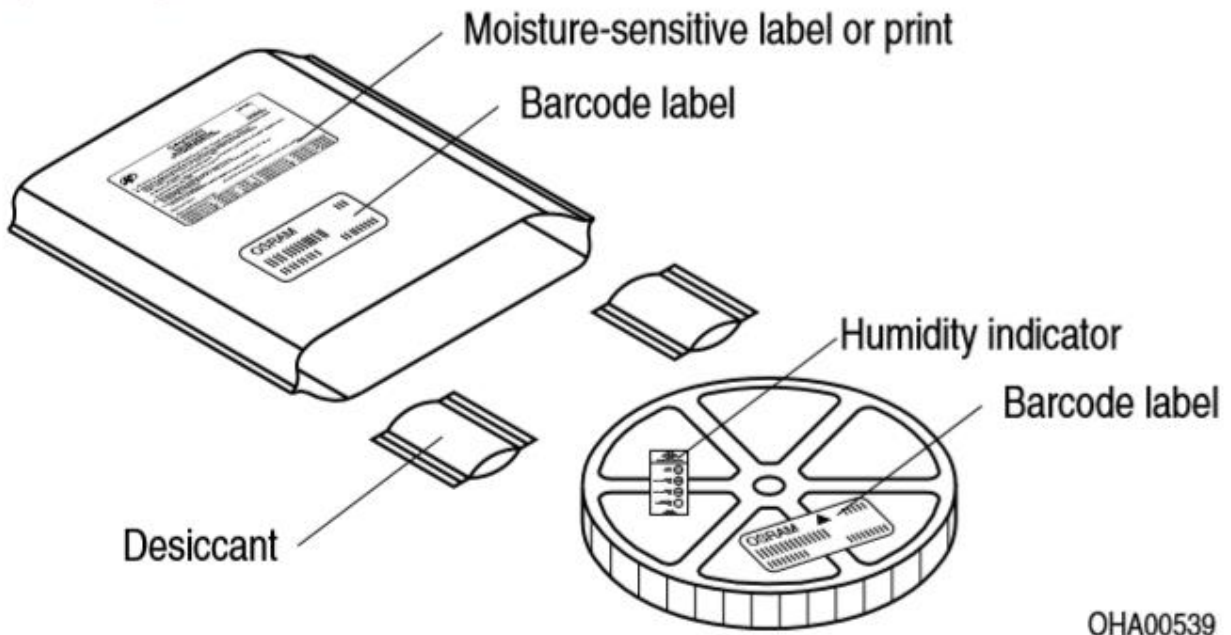
(1T) LOT NO: 1234567890 (9D) D/C: 1234

ML TEMP ST
2 260°C

Pack: RXX
DEMY XXX
X_X123_1234.1234 X

(X)PROD NO:123456789 (Q)QTY: 9999 (G)Group:XX-XX-X-X

Dry Packing Process and Materials



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according to JEDEC-STD-033.

Notes

Depending on the mode of operation, these devices emit highly concentrated visible and non-visible light which can be hazardous to the human eye. Products which incorporate these devices must follow the safety precautions given in IEC 60825-1.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit www.osram-os.com/appnotes

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Glossary

- 1) **Typical Values:** Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- 2) **Testing temperature:** $T_a = 25^\circ\text{C}$
- 3) **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with ± 0.1 and dimensions are specified in mm.
- 4) **Tape and Reel:** All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.

Revision History

Version	Date	Change
0.0	Aug 2 nd , 2019	Initiation of preliminary datasheet
1.0	Feb 25 th , 2020	Application and Ordering information table update

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